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XC7WT14

Triple inverting Schmitt trigger

Rev. 3 — 23 January 2013

Product data sheet

1. General description

The XC7WT14 is a high-speed Si-gate CMOS device. This device provides three inverting buffers with Schmitt trigger action. This device is capable of transforming slowly changing input signals into sharply defined, jitter-free output signals.

2. Features and benefits

- Symmetrical output impedance
- High noise immunity
- ESD protection:
 - ◆ HBM JESD22-A114F exceeds 2000 V
 - ♦ MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101D exceeds 1000 V
- Low power dissipation
- Balanced propagation delays
- Multiple package options
- Specified from −40 °C to +85 °C and −40 °C to +125 °C

3. Applications

- Wave and pulse shaper for highly noisy environment
- Astable multivibrator
- Monostable multivibrator

4. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
XC7WT14DP	–40 °C to +125 °C	TSSOP8	plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm	SOT505-2
XC7WT14DC	–40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads; body width 2.3 mm	SOT765-1
XC7WT14GT	–40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 1 \times 1.95 \times 0.5 mm	SOT833-1
XC7WT14GD	–40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body $3\times2\times0.5~\text{mm}$	SOT996-2



Triple inverting Schmitt trigger

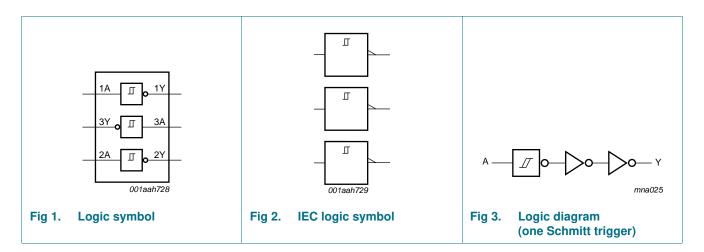
5. Marking

Table 2. Marking codes

Type number	Marking code ^[1]
XC7WT14DP	g14
XC7WT14DC	g14
XC7WT14GT	g14
XC7WT14GD	g14

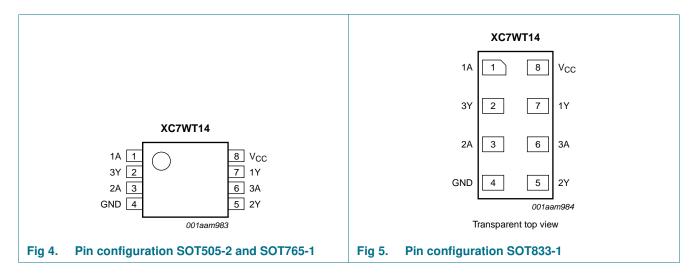
^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

6. Functional diagram



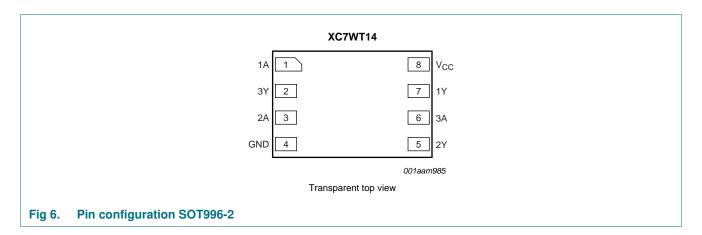
7. Pinning information

7.1 Pinning



XC7WT14

Triple inverting Schmitt trigger



7.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
1A, 2A, 3A	1, 3, 6	data input
GND	4	ground (0 V)
1Y, 2Y, 3Y	7, 5, 2	data output
V _{CC}	8	supply voltage

8. Functional description

Table 4. Function table [1]

Input nA	Output nY
L	Н
H	L

[1] H = HIGH voltage level; L = LOW voltage level

Triple inverting Schmitt trigger

9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+7.0	V
VI	input voltage		-0.5	+7.0	V
I _{IK}	input clamping current	$V_1 < -0.5 V$	-20	-	mA
I_{OK}	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$	[1] -	±20	mA
Io	output current	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$	-	±25	mA
I _{CC}	supply current		-	75	mA
I_{GND}	ground current		-75	-	mA
T _{stg}	storage temperature		-65	+150	°C
P_{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$	[2] _	250	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

10. Recommended operating conditions

Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CC}	supply voltage		4.5	5.0	5.5	V
VI	input voltage		0	-	5.5	V
V _O	output voltage		0	-	V_{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	°C

^[2] For TSSOP8 package: above 55 °C the value of P_{tot} derates linearly at 2.5 mW/K.
For VSSOP8 package: above 110 °C the value of P_{tot} derates linearly at 8 mW/K.
For XSON8 packages: above 118 °C the value of P_{tot} derates linearly with 7.8 mW/K.

Triple inverting Schmitt trigger

11. Static characteristics

Table 7. Static characteristics

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C	to +85 °C	-40 °C t	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
V_{OH}	HIGH-level	$V_I = V_{T+}$ or V_{T-} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	$I_O = -50 \mu A$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O} = -8.0 \text{ mA}$	3.94	-	-	3.8	-	3.70	-	V
V_{OL}	LOW-level	$V_I = V_{T+}$ or V_{T-} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	$I_O = 50 \mu A$	-	0	0.1	-	0.1	-	0.1	V
		$I_{O} = 8.0 \text{ mA}$	-	-	0.36	-	0.44	-	0.55	V
II	input leakage current	$V_I = 5.5 \text{ V or GND};$ $V_{CC} = 0 \text{ V to } 5.5 \text{ V}$	-	-	0.1	-	1.0	-	2.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	1.0	-	10	-	40	μΑ
ΔI_{CC}	additional supply current	per input pin; $V_I = 3.4 \text{ V}$; other inputs at V_{CC} or GND; $I_O = 0 \text{ A}$; $V_{CC} = 5.5 \text{ V}$	-	-	1.35	-	1.5	-	1.5	mA
C _I	input capacitance		-	1.5	10	-	10	-	10	pF

Triple inverting Schmitt trigger

11.1 Transfer characteristics

Table 8. Transfer characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V). See Figure 9 and Figure 10.

Symbol	Parameter	Conditions		25 °C			o +85 °C	-40 °C t	Unit	
			Min	Тур	Max	Min	Max	Min	Max	
V_{T+}	positive-going threshold voltage	$V_{CC} = 4.5 \text{ V}$	-	-	2.0	-	2.0	-	2.0	V
		V _{CC} = 5.5 V	-	-	2.0	-	2.0	-	2.0	٧
V_{T-}	negative-going threshold voltage	$V_{CC} = 4.5 \text{ V}$	0.5	-	-	0.5	-	0.5	-	V
		V _{CC} = 5.5 V	0.6	-	-	0.6	-	0.6	-	٧
V_{H}	hysteresis voltage	$V_{CC} = 4.5 \text{ V}$	0.4	-	1.4	0.4	1.4	0.35	1.4	٧
		$V_{CC} = 5.5 \text{ V}$	0.4	-	1.6	0.4	1.6	0.35	1.6	٧

12. Dynamic characteristics

Table 9. Dynamic characteristics

GND = 0 V; for test circuit see Figure 8.

Symbol	Parameter	Conditions		25 °C			o +85 °C	-40 °C to	Unit	
			Min	Тур	Max	Min	Max	Min	Max	
t _{pd}	propagation	nA to nY; <u>Figure 7</u> [1] [2]								
	delay	C _L = 15 pF	-	4.1	7.0	1.0	8.0	1.0	9.0	ns
		C _L = 50 pF	-	5.9	8.5	1.0	10.0	1.0	11.0	ns
C _{PD}	power dissipation capacitance	per buffer; [3] $V_I = GND \text{ to } V_{CC}$	-	12	-	-	-	-	-	pF

^[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

$$P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$$
 where:

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V;

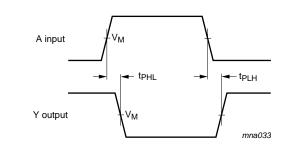
 $\Sigma(C_L\times V_{CC}{}^2\times f_o)$ = sum of the outputs.

^[2] Typical values are measured at $V_{CC} = 5.0 \text{ V}$.

^[3] C_{PD} is used to determine the dynamic power dissipation P_D (μW).

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13. Waveforms

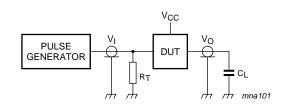


Measurement points are given in Table 10.

Fig 7. The input (nA) to output (nY) propagation delays

Table 10. Measurement points

Type number	Input		Output
	V _I	V _M	V _M
XC7WT14	GND to 3.0 V	1.5 V	$0.5 \times V_{CC}$



Test data is given in Table 11.

Definitions for test circuit:

 C_L = Load capacitance including jig and probe capacitance.

 $R_{T} = \mbox{Termination} \ \mbox{resistance} \ \mbox{should} \ \mbox{be} \ \mbox{equal to output impedance} \ \mbox{Z}_{0} \ \mbox{of the pulse} \ \mbox{generator}.$

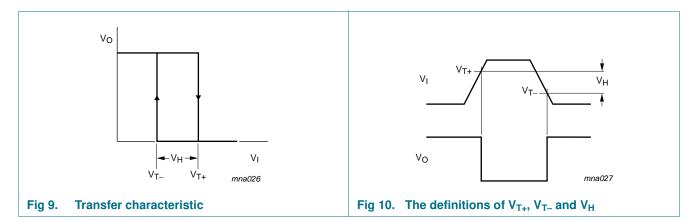
Fig 8. Test circuit for measuring switching times

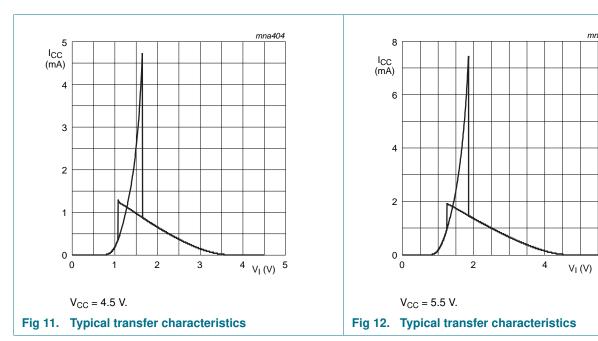
Table 11. Test data

Туре	Input		Load	Test
	VI	t _r , t _f	CL	
XC7WT14	3.0 V	≤ 3.0 ns	15 pF, 50 pF	t _{PLH} , t _{PHL}

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13.1 Transfer characteristic waveforms





6

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14. Application information

The slow input rise and fall times cause additional power dissipation, which can be calculated using the following formula:

 $P_{add} = f_i \times (t_r \times \Delta I_{CC(AV)} + t_f \times \Delta I_{CC(AV)}) \times V_{CC}$ where:

 P_{add} = additional power dissipation (μW);

 $f_i = input frequency (MHz);$

 t_r = input rise time (ns); 10 % to 90 %;

 t_f = input fall time (ns); 90 % to 10 %;

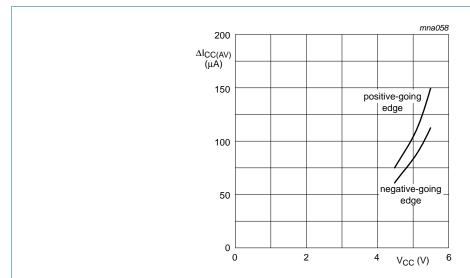
 $\Delta I_{CC(AV)}$ = average additional supply current (μA).

 $\Delta I_{CC(AV)}$ differs with positive or negative input transitions, as shown in Figure 13.

For XC7WT14 used in relaxation oscillator circuit, see Figure 14.

Note to the application information:

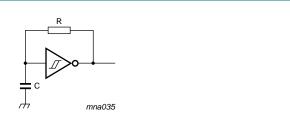
1. All values given are typical unless otherwise specified.



Linear change of V_{I} between $0.1V_{CC}$ to $0.9V_{CC}$

Fig 13. Average additional I_{CC}

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$$f = \frac{1}{T} \approx \frac{1}{0.60 \times RC}$$

Fig 14. Relaxation oscillator using the XC7WT14

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15. Package outline

TSSOP8: plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm SOT505-2

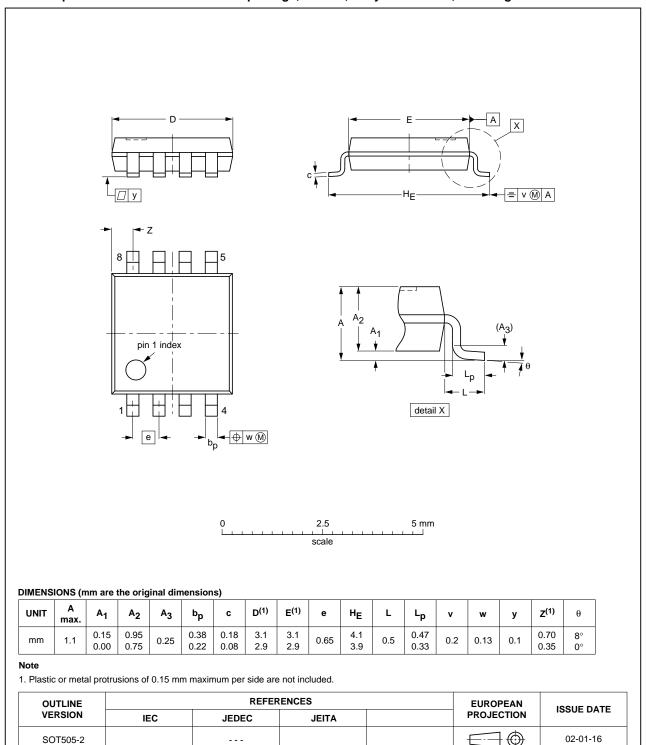


Fig 15. Package outline SOT505-2 (TSSOP8)

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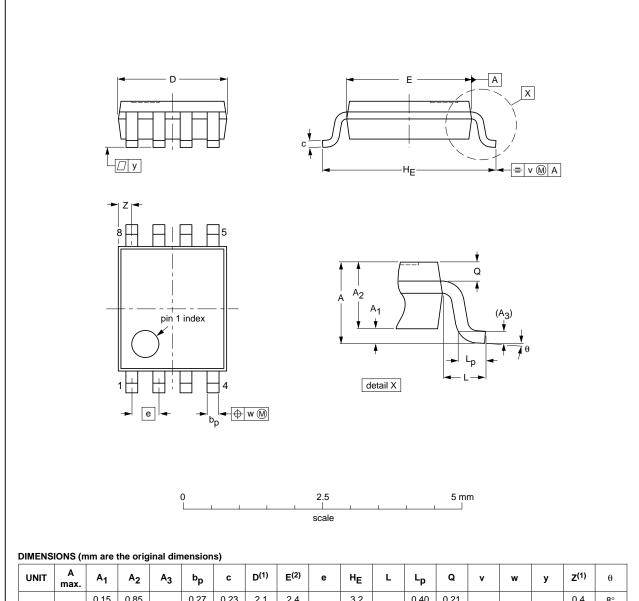
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VSSOP8: plastic very thin shrink small outline package; 8 leads; body width 2.3 mm

SOT765-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽²⁾	e	HE	L	Lp	ď	v	w	у	Z ⁽¹⁾	θ
mm	1	0.15 0.00	0.85 0.60	0.12	0.27 0.17	0.23 0.08	2.1 1.9	2.4 2.2	0.5	3.2 3.0	0.4	0.40 0.15	0.21 0.19	0.2	0.13	0.1	0.4 0.1	8° 0°

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT765-1		MO-187				02-06-07

Fig 16. Package outline SOT765-1 (VSSOP8)

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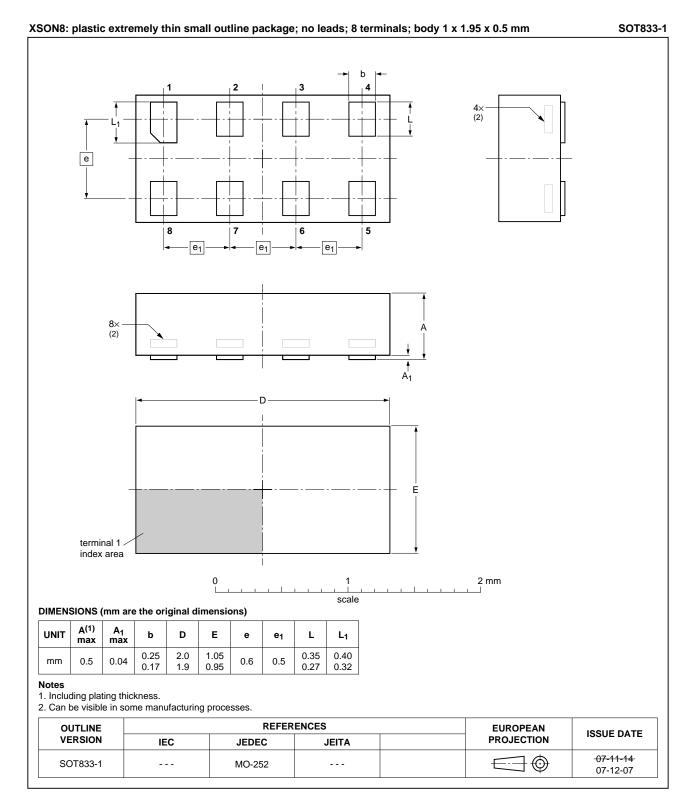


Fig 17. Package outline SOT833-1 (XSON8)

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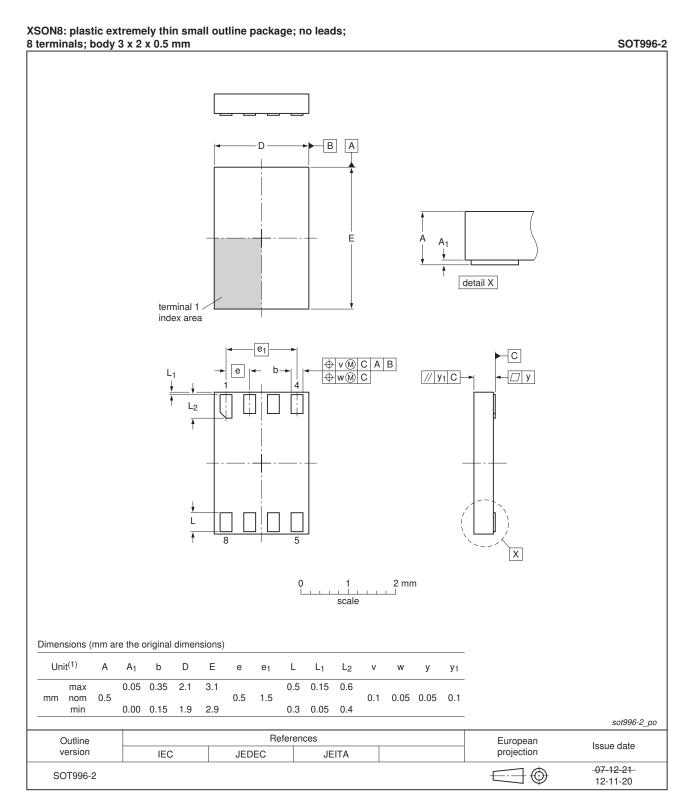


Fig 18. Package outline SOT996-2 (XSON8)

XC7WT14

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16. Abbreviations

Table 12. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

17. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
XC7WT14 v.3	20130123	Product data sheet	-	XC7WT14 v.2
Modifications:	 For type nur 	nber XC7WT14GD XSON8U h	as changed to XSO	N8.
XC7WT14 v.2	20111103	Product data sheet	-	XC7WT14 v.1
XC7WT14 v.1	20110119	Product data sheet	-	-

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18. Legal information

18.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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XC7WT14

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Triple inverting Schmitt trigger

20. Contents

1	General description 1
2	Features and benefits
3	Applications
4	Ordering information 1
5	Marking 2
6	Functional diagram 2
7	Pinning information 2
7.1	Pinning
7.2	Pin description
8	Functional description 3
9	Limiting values 4
10	Recommended operating conditions 4
11	Static characteristics 5
11.1	Transfer characteristics 6
12	Dynamic characteristics 6
13	Waveforms
13.1	Transfer characteristic waveforms 8
14	Application information 9
15	Package outline
16	Abbreviations
17	Revision history 15
18	Legal information 16
18.1	Data sheet status
18.2	Definitions
18.3	Disclaimers
18.4	Trademarks17
19	Contact information 17
20	Contents

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